# NSN 5962-01-372-5546

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Between 1.270 inches and 1.290 inches

**Body Width:** 

Between 0.590 inches and 0.610 inches

**Body Height:** 

Between 0.205 inches and 0.225 inches

### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **End Application:**

Milstar

#### **Features Provided:**

Burn in, mil-std-883, class b and compatible cmos and electrostatic sensitive and high speed and hermetically sealed and open drain

#### **Inclosure Material:**

Ceramic

### **Inclosure Configuration:**

Dual-in-line

# **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

# **Criticality Code Justification:**

Feat

### **Case Outline Source And Designator:**

D-3 mil-m-38510

# **Current Rating Per Characteristic:**

50.00 microamperes input

# **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Microcircuit, digital, memory; microcircuit, rescreened

# Voltage Rating And Type Per Characteristic:

-0.5 volts total supply and 7.0 volts total supply

# **Memory Device Type:**

Rom

### **Special Features:**

Electrostatic discharge sens/hardness critical; selected item made from rc258-0147-010 cage 95105, rescreened from 995-9501-020 cage 95105, which is idt71681sa-45dbrt

## **Nuclear Hardness Critical Feature:**

Hardened

# **Special Test Features:**

Selected and tested for wafer lot hardness

# **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type A	and Quantity	<b>/:</b>
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24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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